

TC74VCX16600FT

Low-Voltage 18-Bit Universal Bus Transceiver with 3.6-V Tolerant Inputs and Outputs

The TC74VCX16600FT is a high performance CMOS 18-bit universal bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

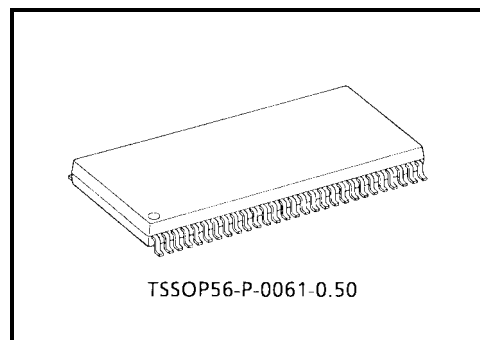
Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CKAB and CKBA) inputs. The clock can be controlled by the clock-enable (CKENAB and CKENBA) inputs.

For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CKAB is held at a high or low logic level. If LEAB is low, the A-bus data is stored in the latch/flip-flop on the high-to-low transition of CKAB.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, CKBA, and CKENBA.

When the OE input is high, the outputs are in a high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

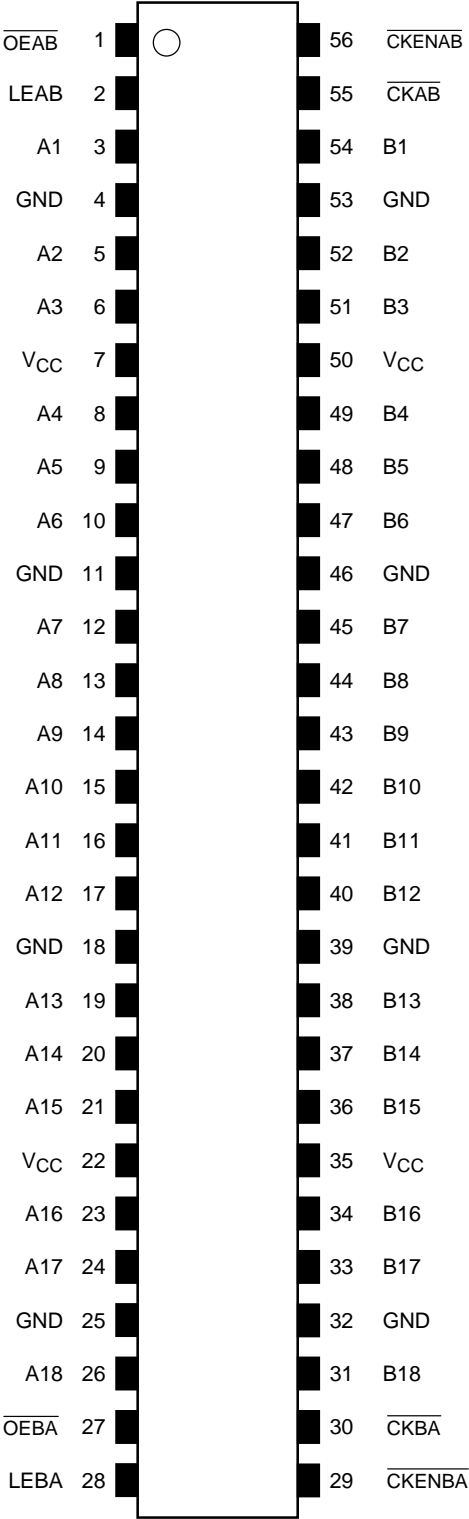
Features

- Low-voltage operation: $V_{CC} = 1.8$ to 3.6 V
- High-speed operation: $t_{pd} = 2.9$ ns (max) ($V_{CC} = 3.0$ to 3.6 V)
 : $t_{pd} = 3.7$ ns (max) ($V_{CC} = 2.3$ to 2.7 V)
 : $t_{pd} = 7.8$ ns (max) ($V_{CC} = 1.8$ V)
- Output current: $I_{OH}/I_{OL} = \pm 24$ mA (min) ($V_{CC} = 3.0$ V)
 : $I_{OH}/I_{OL} = \pm 18$ mA (min) ($V_{CC} = 2.3$ V)
 : $I_{OH}/I_{OL} = \pm 6$ mA (min) ($V_{CC} = 1.8$ V)
- Latch-up performance: ± 300 mA
- ESD performance: Machine model $> \pm 200$ V
 : Human body model $> \pm 2000$ V
- Package: TSSOP (thin shrink small outline package)
- Bidirectional interface between 2.5 V and 3.3 V signals.
- 3.6-V tolerant function and power down-protection provided on all inputs and outputs

Note 1: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

All floating (high impedance) bus pins must have their input level fixed by means of pull-up or pull-down resistors.

Pin Assignment (top view)



Truth Table (A bus → B bus)

Inputs					Outputs B
$\overline{\text{CKENAB}}$	$\overline{\text{OEAB}}$	LEAB	$\overline{\text{CKAB}}$	A	
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B0 (Note 3)
H	L	L	X	X	B0 (Note 3)
L	L	L	\downarrow	L	L
L	L	L	\downarrow	H	H
L	L	L	H	X	B0 (Note 2)
L	L	L	L	X	B0 (Note 2)

Note 2: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKBA}}$ was low or high before LEBA went low.

Note 3: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKENAB}}$ was low or high before LEAB went low.

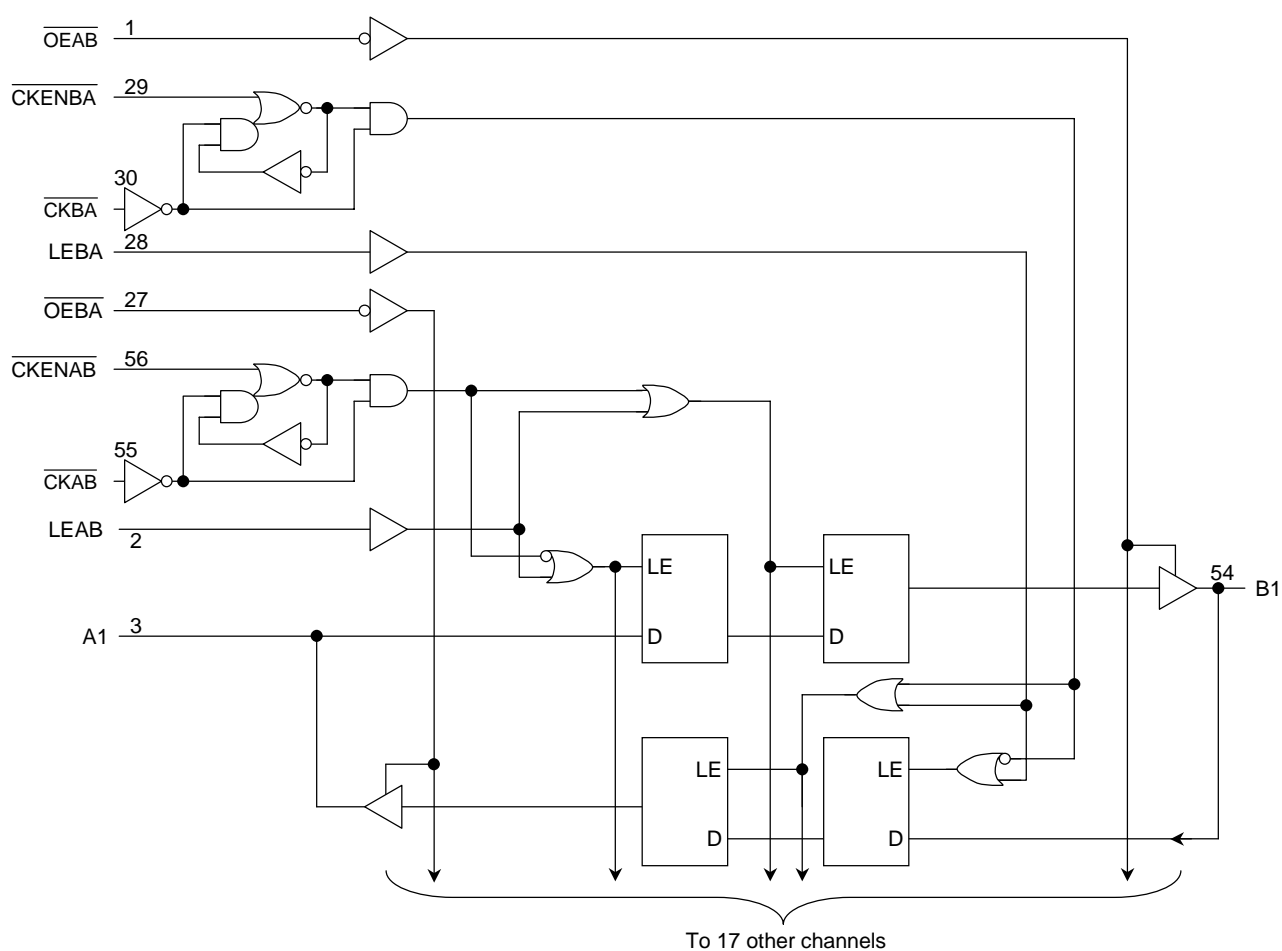
Truth Table (B bus → A bus)

Inputs					Outputs A
$\overline{\text{CKENBA}}$	$\overline{\text{OEBA}}$	LEBA	$\overline{\text{CKBA}}$	B	
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	A0 (Note 5)
H	L	L	X	X	A0 (Note 5)
L	L	L	\downarrow	L	L
L	L	L	\downarrow	H	H
L	L	L	H	X	A0 (Note 4)
L	L	L	L	X	A0 (Note 4)

Note 4: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKBA}}$ was low or high before LEBA went low.

Note 5: Output level before the indicated steady-state input conditions were established, provided that $\overline{\text{CKENAB}}$ was low or high before LEAB went low.

System Diagram



Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	−0.5 to 4.6	V
DC input voltage (\overline{OEAB} , \overline{OEBA} , $LEAB$, $LEBA$, $CKAB$, $CKBA$, $CKENAB$, $CKENBA$)	V_{IN}	−0.5 to 4.6	V
DC bus I/O voltage	$V_{I/O}$	−0.5 to 4.6 (Note 6)	V
		−0.5 to $V_{CC} + 0.5$ (Note 7)	
Input diode current	I_{IK}	−50	mA
Output diode current	I_{OK}	±50 (Note 8)	mA
DC output current	I_{OUT}	±50	mA
Power dissipation	P_D	400	mW
DC V_{CC} /ground current per supply pin	I_{CC}/I_{GND}	±100	mA
Storage temperature	T_{stg}	−65 to 150	°C

Note 6: OFF state

 Note 7: High or low state. I_{OUT} absolute maximum rating must be observed.

 Note 8: $V_{OUT} < GND$, $V_{OUT} > V_{CC}$
Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Power supply voltage	V_{CC}	1.8 to 3.6	V
		1.2 to 3.6 (Note 9)	
Input voltage (\overline{OEAB} , \overline{OEBA} , $LEAB$, $LEBA$, $CKAB$, $CKBA$, $CKENAB$, $CKENBA$)	V_{IN}	−0.3 to 3.6	V
Bus I/O voltage	$V_{I/O}$	0 to 3.6 (Note 10)	V
		0 to V_{CC} (Note 11)	
Output current	I_{OH}/I_{OL}	±24 (Note 12)	mA
		±18 (Note 13)	
		±6 (Note 14)	
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 15)	ns/V

Note 9: Data retention only

Note 10: OFF state

Note 11: High or low state

 Note 12: $V_{CC} = 3.0$ to 3.6 V

 Note 13: $V_{CC} = 2.3$ to 2.7 V

 Note 14: $V_{CC} = 1.8$ V

 Note 15: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics ($T_a = -40$ to 85°C , $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	—		2.7 to 3.6	2.0	—	V
	L-level	V _{IL}	—		2.7 to 3.6	—	0.8	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	—	V
				I _{OH} = -12 mA	2.7	2.2	—	
				I _{OH} = -18 mA	3.0	2.4	—	
				I _{OH} = -24 mA	3.0	2.2	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	—	0.2	
				I _{OL} = 12 mA	2.7	—	0.4	
				I _{OL} = 18 mA	3.0	—	0.4	
				I _{OL} = 24 mA	3.0	—	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V	2.7 to 3.6	—	±5.0	μA	
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V	2.7 to 3.6	—	±10.0	μA	
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V	0	—	10.0	μA	
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND	2.7 to 3.6	—	20.0	μA	
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V	2.7 to 3.6	—	±20.0		
Increase in I _{CC} per unit		ΔI _{CC}	V _{IH} = V _{CC} - 0.6 V	2.7 to 3.6	—	750		

DC Characteristics ($T_a = -40$ to 85°C , $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
					V _{CC} (V)			
Input voltage	H-level	V _{IH}	—		2.3 to 2.7	1.6	—	V
	L-level	V _{IL}	—		2.3 to 2.7	—	0.7	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	—	V
				I _{OH} = -6 mA	2.3	2.0	—	
				I _{OH} = -12 mA	2.3	1.8	—	
				I _{OH} = -18 mA	2.3	1.7	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.3 to 2.7	—	0.2	
				I _{OL} = 12 mA	2.3	—	0.4	
				I _{OL} = 18 mA	2.3	—	0.6	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	—	±5.0	μA
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		2.3 to 2.7	—	±10.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		2.3 to 2.7	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		2.3 to 2.7	—	±20.0	

DC Characteristics ($T_a = -40$ to 85°C , $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$)

Characteristics		Symbol	Test Condition		Min	Max	Unit	
								V _{CC} (V)
Input voltage	H-level	V _{IH}	—		1.8 to 2.3	0.7 × V _{CC}	—	V
	L-level	V _{IL}	—		1.8 to 2.3	—	0.2 × V _{CC}	
Output voltage	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −100 μA	1.8	V _{CC} − 0.2	—	V
				I _{OH} = −6 mA	1.8	1.4	—	
	L-level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	—	0.2	
				I _{OL} = 6 mA	1.8	—	0.3	
Input leakage current		I _{IN}	V _{IN} = 0 to 3.6 V		1.8	—	±5.0	μA
3-state output OFF state current		I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 3.6 V		1.8	—	±10.0	μA
Power-off leakage current		I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current		I _{CC}	V _{IN} = V _{CC} or GND		1.8	—	20.0	μA
			V _{CC} ≤ (V _{IN} , V _{OUT}) ≤ 3.6 V		1.8	—	±20.0	

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Maximum clock frequency	f_{\max}	Figure 1, Figure 3	1.8	100	—	MHz
			2.5 ± 0.2	200	—	
			3.3 ± 0.3	250	—	
Propagation delay time (An, Bn-Bn, An)	t_{pLH} t_{pHL}	Figure 1, Figure 2	1.8	1.5	7.8	ns
			2.5 ± 0.2	0.8	3.7	
			3.3 ± 0.3	0.6	2.9	
Propagation delay time (\overline{CKAB} , \overline{CKBA} -Bn, An)	t_{pLH} t_{pHL}	Figure 1, Figure 3	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	5.0	
			3.3 ± 0.3	0.6	3.5	
Propagation delay time (LEAB, LEBA-Bn, An)	t_{pLH} t_{pHL}	Figure 1, Figure 4	1.8	1.5	8.8	ns
			2.5 ± 0.2	0.8	4.4	
			3.3 ± 0.3	0.6	3.5	
Output enable time (\overline{OEAB} , \overline{OEBA} -Bn, An)	t_{pZL} t_{pZH}	Figure 1, Figure 6	1.8	1.5	9.8	ns
			2.5 ± 0.2	0.8	4.9	
			3.3 ± 0.3	0.6	3.8	
Output disable time (\overline{OEAB} , \overline{OEBA} -Bn, An)	t_{pLZ} t_{pHZ}	Figure 1, Figure 6	1.8	1.5	7.6	ns
			2.5 ± 0.2	0.8	4.2	
			3.3 ± 0.3	0.6	3.7	
Minimum pulse width	t_W (H) t_W (L)	Figure 1, Figure 3, Figure 4	1.8	4.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum set-up time	t_s	Figure 1, Figure 3, Figure 4, Figure 5	1.8	2.5	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.5	—	
Minimum hold time	t_h	Figure 1, Figure 3, Figure 4, Figure 5	1.8	2.0	—	ns
			2.5 ± 0.2	1.5	—	
			3.3 ± 0.3	1.0	—	
Output to output skew	t_{osLH} t_{osHL}	(Note 16)	1.8	—	0.5	ns
			2.5 ± 0.2	—	0.5	
			3.3 ± 0.3	—	0.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 16: Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics
(Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	V _{IH} = 1.8 V, V _{IL} = 0 V (Note 17)	1.8	0.25	V
		V _{IH} = 2.5 V, V _{IL} = 0 V (Note 17)	2.5	0.6	
		V _{IH} = 3.3 V, V _{IL} = 0 V (Note 17)	3.3	0.8	
Quiet output minimum dynamic V _{OL}	V _{OLV}	V _{IH} = 1.8 V, V _{IL} = 0 V (Note 17)	1.8	−0.25	V
		V _{IH} = 2.5 V, V _{IL} = 0 V (Note 17)	2.5	−0.6	
		V _{IH} = 3.3 V, V _{IL} = 0 V (Note 17)	3.3	−0.8	
Quiet output minimum dynamic V _{OH}	V _{OHV}	V _{IH} = 1.8 V, V _{IL} = 0 V (Note 17)	1.8	1.5	V
		V _{IH} = 2.5 V, V _{IL} = 0 V (Note 17)	2.5	1.9	
		V _{IH} = 3.3 V, V _{IL} = 0 V (Note 17)	3.3	2.2	

Note 17: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Typ.	Unit
Input capacitance	C _{IN}	—	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	—	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note 18)	1.8, 2.5, 3.3	20	pF

 Note 18: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/18 \text{ (per bit)}$$

AC Test Circuit

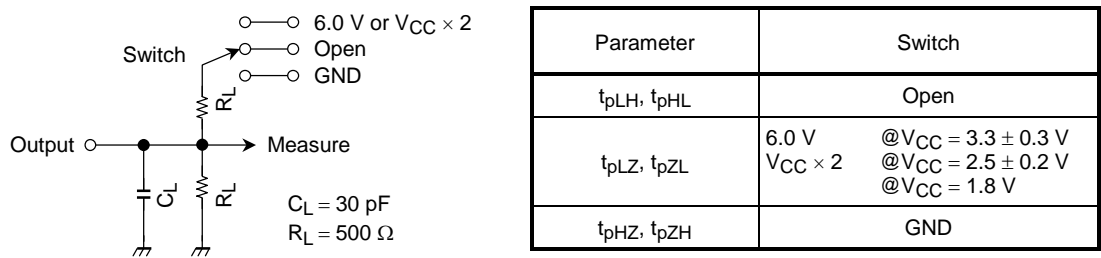


Figure 1

AC Waveform

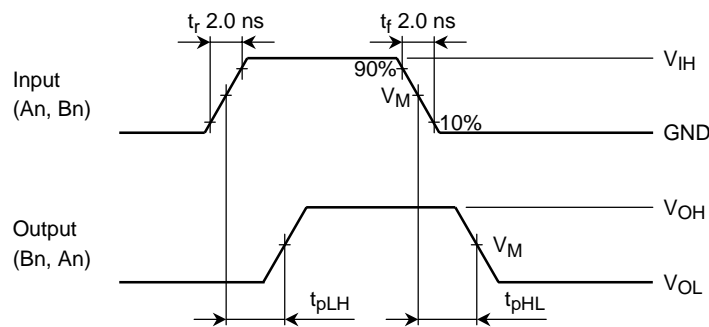


Figure 2 t_{pLH} , t_{pHL}

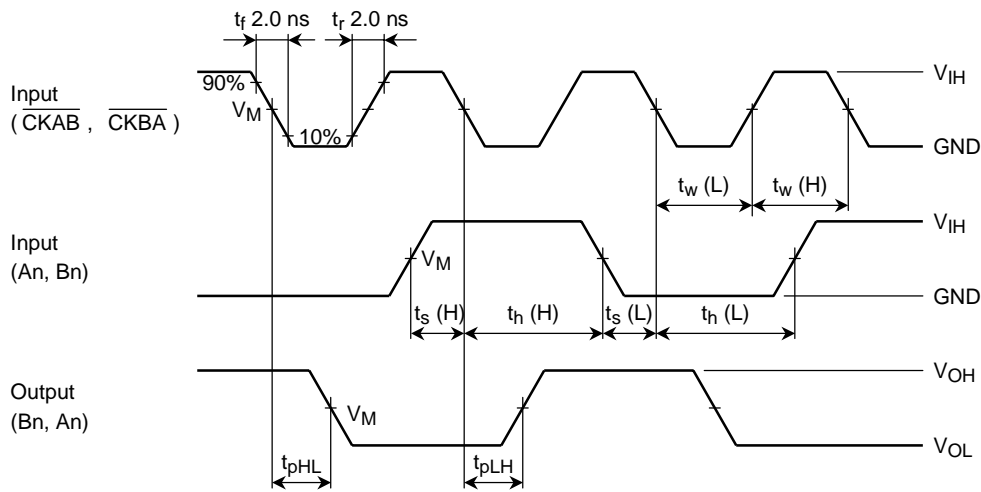


Figure 3 t_{pLH} , t_{pHL} , t_w , t_s , t_h

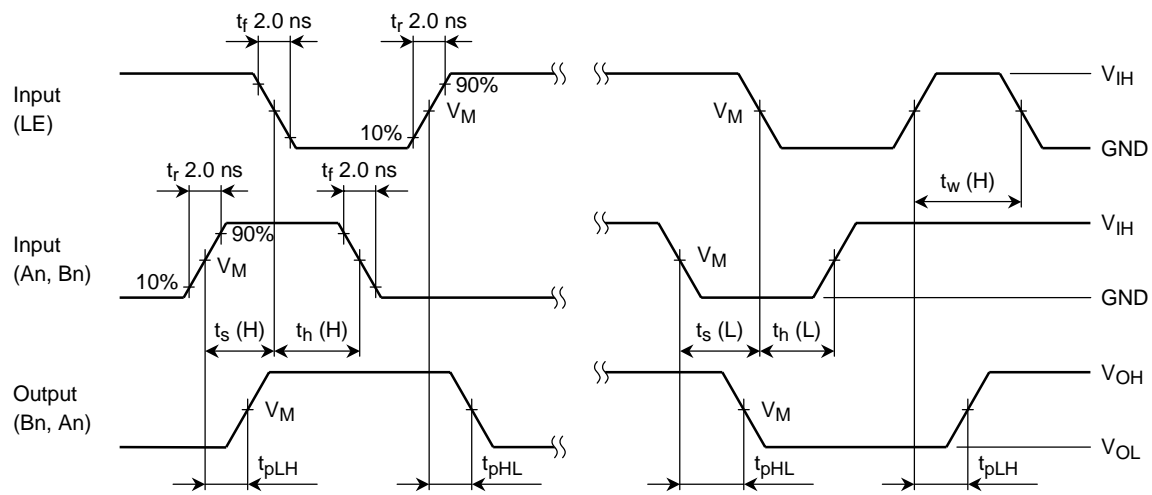


Figure 4 t_{pLH} , t_{pHL} , t_w , t_s , t_h

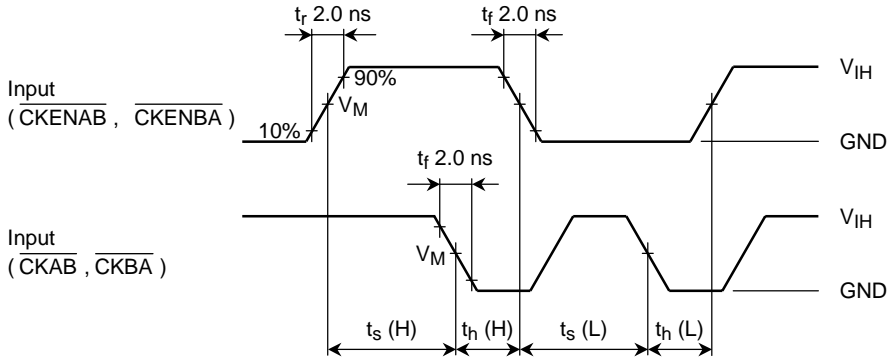


Figure 5 t_s , t_h

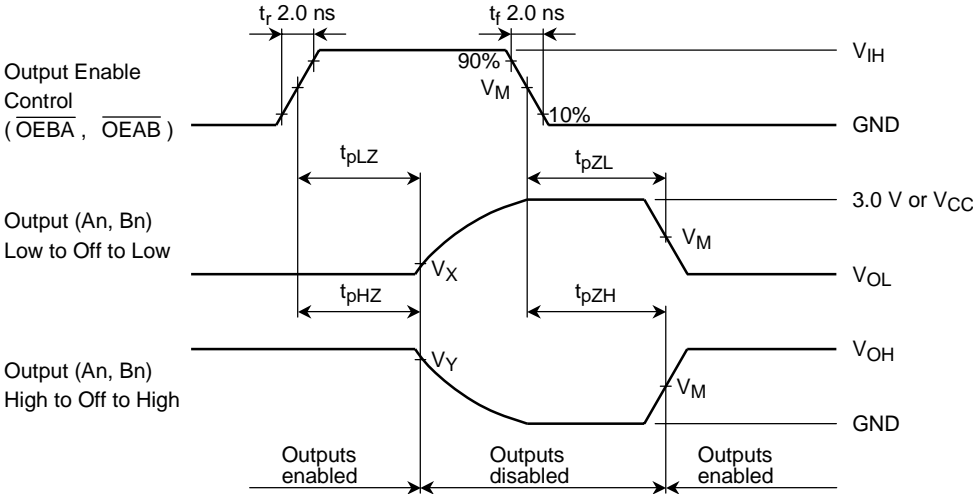


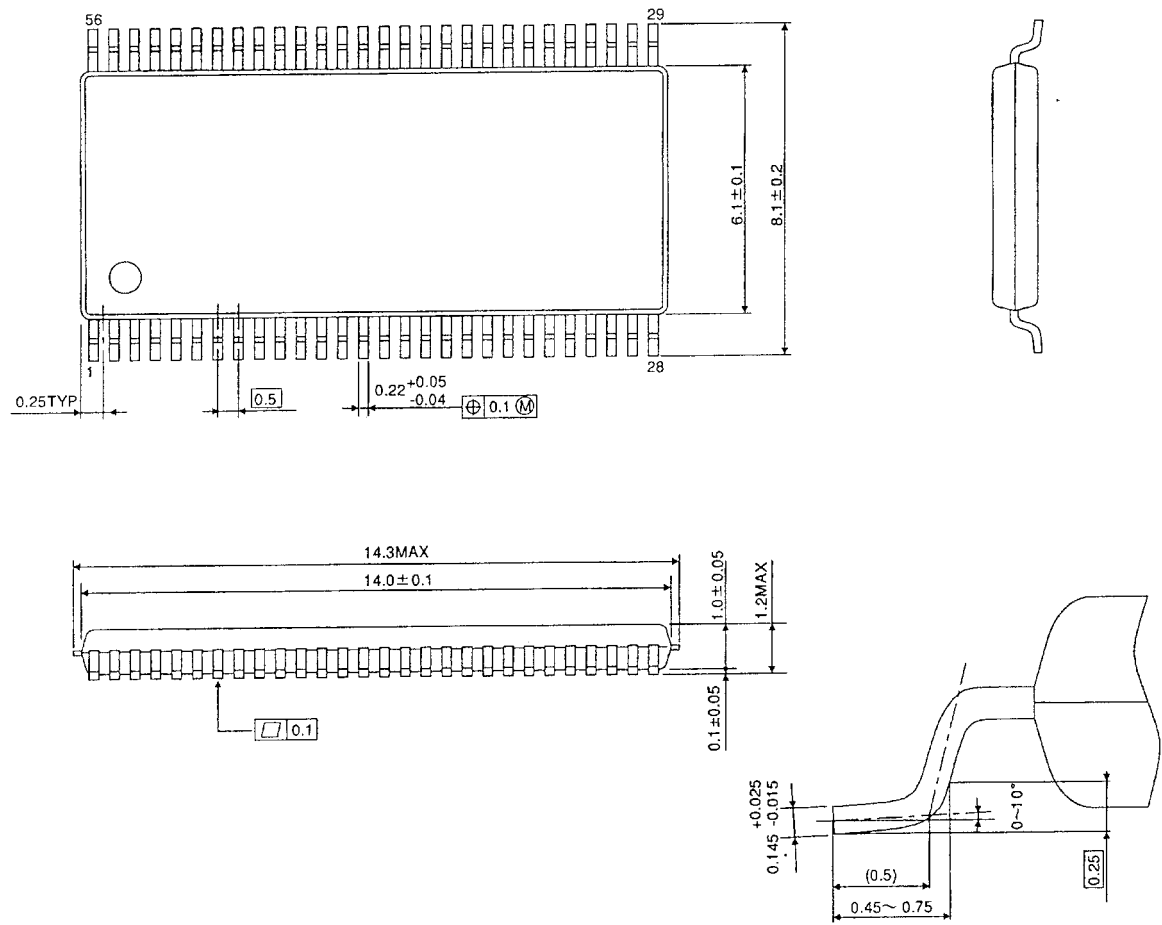
Figure 6 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$
V_X	$V_{OL} + 0.3 \text{ V}$	$V_{OL} + 0.15 \text{ V}$	$V_{OL} + 0.15 \text{ V}$
V_Y	$V_{OH} - 0.3 \text{ V}$	$V_{OH} - 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$

Package Dimensions

TSSOP56-P-0061-0.50

Unit : mm



Weight: 0.25g (typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

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